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IM6102 Memory Extension/ DMA Controller/ Interval Timer (MEDIC)

FEATURES

- Provides Extended Memory Address to 32K Words
- Simultaneous DMA Provides Simultaneous DMA Channel that Uses DX Bus During Second Half of a Cycle to Access Memory
- DMA Channel Can be Used for Dynamic RAM Refresh
- 12-Bit Programmable Interval Timer
- Direct Interface with IM6100 Microprocessor Via Bidirectional DX Bus and Handshake Lines
- Hardware Reset
- 28 Different I/O Instructions

GENERAL DESCRIPTION

The IM6102 is a multi-function peripheral controller chip incorporating functions such as memory extension, direct memory access control, and a programmable real time clock.

The IM6102 provides necessary control to address up to 32K words of memory, and its DMA channel can be used with Dynamic RAM Components for "transparent refresh". The programmable real time clock is 12-bit long, and its output frequency can be programmed for 5 decades.

It features a high degree of system integration, putting into one chip all the functions which are normally available in three or more LSI circuits. As a result of this large integration, the user can design and produce a compact microcomputer with minicomputer performance.



	•	40	
DMAEN	2	39	
	3	38	EMA2
MEMSEL	4	37	EMA1
IFETCH	5	36	EMAO
MEMSEL*	6	35	SKP/INT
RESET	7	34	
ᅋᇊ	8	33	
XTA	9	32	<u>]</u>
LXMAR	10	31	Dosc оит
LXMAR*	11	30	DEVSEL
STC*□	12	29	
хтс 🛙	13	28]DX11
CLOCK	14	27	DX10
SKP/INTX	15	26	GND
DX0 🖸	16	25	DX9
DX1	17	24	DX8
DX2	18	23	
DX3	19	22	DX6
DX4	20	21	DX5

ORDERING INFORMATION

ORDER CODE	IM6102-1	IM6102A	IM6102
PLASTIC PKG.	IM6102-1IPL	IM6102-AIPL	IM6102-IPL
CERAMIC PKG	IM6102-1IDL	IM6102-AIDL	-
MILITARY TEMP.	IM6102-1MDL	IM6102-AMDL	-
MILITARY TEMP. WITH 883B	IM6102-1 MDL/883B	IM6102-AMDL/ 883B	-

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	1. A.	-	
V _{cc} [40	PROUT
DMAEN	2	39	INTONT
DMAGNT	3	38	EMA2
MEMSEL	4	37	EMA1
IFETCH	5	36	EMAO
MEMSEL .	6	35	SKP/INT
RESET	7	34	ॻज़
ŪP 🖸	8	33	
XTA [9	32	<u>]</u> <u></u>
LXMAR	10	31] OSC OUT
LXMAR*	11	30	DEVSEL
XTC*	12	29	oscin
хтс [13	28	DX11
CLOCK	14	27	DX10
SKP/INTX	15	26	GND
DX0	16	25	DX9
DX1	17	24	DX8
DX2	18	23	DX7
DX3	19	22	DX6
DX4	20	21	DX5

IM6102 FUNCTIONAL PIN DESCRIPTION

	Pin Number	Symbol	Input/ Output	Description
	1	Vcc	1.1	Supply voltage
	2	DMAEN	t	Enable the IM6102 DMA chan- nel to transfer data
	3	DMAGNT	1 I 1	Direct memory access grant from CPU
•	4	MEMSEL	1	Memory select for read or write from CPU
	5	IFETCH	ig I≜	CPU flag indicating instruction fetch cycle
	6	MEMSEL	0.	Memory select generated by the IM6102
	7,	RESET	1. 1	Asynchronous reset will clear Instruction Field to 0 ₈ , disable
		2	la de terte Contra terte	all interrupts, initialize DMA port to READ/REFRESH, ini- tialize timer to "aton", "divide
	-	1. g. s. s.		by 2 ¹² mode" and "enable divide counters"
	` 8	UP	0	User pulse (read or write)
	9	XTA	1.	CPU external minor cycle tim- ing signal
	10	LXMAR		A falling edge of LXMAR pulse from CPU will load external
			1. S. A.	memory address register

Pin Number	Symbol	Input/ Output	Description
11	LXMAR*	0	LXMAR generated by the IM6102
12	XTC.	0	XTC generated by the IM6102
13	хтс	1	CPU external minor cycle tim- ing signal
14	CLOCK	1	Oscillator OUT pulses from CPU for timing the IM6102
· · ·			DMA transfers.
15	SKP/INTX		Multiplexed SKP/INT line from lower priority devices
16	DX0	1/0	Most significant bit of the 12-bit multiplexed address and data I/O bus
17	DX1	· I/O	See pin 16-DX0
18	DX2	1/0	See pin 16-DX0
19	DX3	1/0	See pin 16-DX0
20	DX4	I/O	See pin 16-DX0
21	DX5	. I/O	See pin 16-DX0
22	DX6	1/0	See pin 16-DX0
23	DX7	1/0	See pin 16-DX0
24	5X8	1/0	See pin 16-DX0
25	DX9	1/0	See pin 16-DX0
26	GND	· I/O	Power Supply
27	DX10	I/O	See pin 16-DX0
28	DX11	1/0	See pin 16-DX0
29 .	OSCIN	Ì	Crystal input for timer oscil- lator
30	DEVSEL	$z = \mathbf{L}_{1}^{\prime}$	Device select for read or write from CPU
31	OSC OUT	° 0	See pin 29
32	C ₀	0	Control lines to CPU determin- ing type of peripheral data transfer
33	C ₁	0	See pin 32-C ₀
34	C ₂	0	See pin 32-C ₀
35	SKP/INT	· O	Multiplexed SKP/INT input to the CPU
36	ΕΜΑΟ	· 0	Extended memory address field (most significant bit)
37	EMA1	•• O :	Extended memory address field
38	EMA2	0	Extended memory address field
39	INTGNT	. ji	CPU interrupt grant
40	PROUT	0	Priority out for vectored inter-

NOTE: All DX lines are bidirectional with three-state outputs: Pins 6, 8, 11, 12, 35, 40 have active pullups; pins 32, 33, 34 have open drain outputs; pin 15 has a resistive input pullup; all inputs are protected with resistors and clamp diodes.

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IM6102

ARCHITECTURE

The IM6102 is composed of three distinct functions:

- a) A DMA port that uses the bus during the second half of a cycle to read, write, or refresh memory. The DMA port logic includes a word count register WC, a current address register CA, an extended current address register ECA, and a DMA status register.
- b) An extended memory address controller that augments the 12-bit addresses generated by the IM6100 microprocessor by supplying a 3-bit address field that may be decoded to select one of eight 4096 word memory fields. The memory extension controller logic consists of an instruction field register IF, a data field register DF, an instruction buffer register IB, and a save field register SF.
- c) A realtime clock whose mode and time base rate may be programmed by the user. The clock logic includes a clock enable register CE, a clock buffer register CB, a clock counter register CC, and a time base multiplexer.

A block diagram of the IM6102 is shown in Figure 1.

The IM6102 registers are summarized as follows:

A. Simultaneous DMA Channel (Figure 3)

CURRENT ADDRESS (CA) REGISTER

This register is a 12-bit presettable binary counter. At the beginning of a SDMA transfer, the current address must be set to the first location to be accessed. The content of the CA register is incremented by 1 after a SDMA transfer, and the incremented value is used as the address of the memory location with which the next transfer will be performed.

EXTENDED CURRENT ADDRESS (ECA) REGISTER

This is a 3-bit presettable binary counter and if the carry enable bit of the DMA status register is set, the 12-bit CA register and the 3 ECA bits are treated as one 15-bit register with the ECA bits most significant. If memory field 7 (all 3 bits at logic one) is selected, the ECA cannot increment, but will wrap around in field 7 and an F7 error (F7E) will occur. The Interrupt Enable bit IE in SR11must be set to enable F7E interrupts. If enabled the F7E will request an interrupt. If the carry enable bit CE in SR9 is not set, the ECA is not incremented when CA goes from 77778 to 0000g.

WORD COUNT (WC) REGISTER

A 12-bit presettable binary counter is used as a word counter. At the beginning of a SDMA transfer, the two's complement of the number of 12-bit words to be transferred must be loaded into the WC. If enabled this will initiate the SDMA operation. The WC register is incremented by 1 after a SDMA transfer. If this value becomes zero, word count overflow has occurred and if the IE bit in SR11 is set, interrupts are enabled and an interrupt is requested. Unless instructed to be in the continuous run mode, a WC overflow inhibits further transfers. The WOF is set when the MSB of the WC register makes a "1" to "0" transition.



FIGURE 1: IM6102 MEMORY EXTENSION/DMA/INTERVAL TIMER CONTROLLER (MEDIC)



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FIGURE 2: MEDIC TIMING FOR DCA I

DMA Status Register

This register consists of 5 control bits and 2 flag bits for the SDMA feature. For a description refer to the register bit assignments.





OPERATION

The IM6102 SDMA channel augments the throughput of the IM6100 during DMA operations by transferring data between memory and peripheral devices simultaneously with normal processor bus usage. In other words, no memory cycles are "stolen" from the processor; but the DMA address and data are transferred on the bus during periods that the DX bus is inactive.

TABLE 3 SDMA INSTRUCTIONS

MNEMONIC	OCTAL CODE	OPERATION
LCAR	6205 ₈	LOAD CURRENT ADDRESS REGISTER (CA) The contents of the AC replace the contents of the CA and the AC is cleared. DMA sequencing is stopped.
RCAR	62158	READ CURRENT ADDRESS REGISTER Description: Contents of CA transferred to AC.
LWCR	62258	LOAD WORD COUNT REGISTER (WC) Description: Contents of AC are transferred to the WORD COUNT REGISTER, the AC is cleared WORD COUNT OVERFLOW (WOF) is cleared and DMA operation started.
LEAR	62N6 ₈	LOAD IMMEDIATE TO EXTENDED CURRENT ADDRESS REGISTER (ECA) Description: Field N of the IOT instruction is transferred to the Extended current address register.
REAR	6235 ₈	READ EXTENDED CA Description: Extended current address register contents OR'd into bits 6, 7, 8, of AC.
LFSR	6245 ₈	LOAD DMA FLAGS and STATUS REGISTER Description: AC bits 7-11 are transferred to the DMA STATUS REGISTER and the AC is cleared.
RFSR	62558	READ DMA FLAGS and STATUS REGISTER Description: DMA Flags and Status Register bits are OR transferred into AC bits 5-11 and Field 7 wraparound error (F7E) is cleared.
SKOF	6265 ₈	SKIP ON OVERFLOW INTERRUPT Description: The PC is incremented by 1 if a word count register overflow interrupt condition is present causing next instruction to be skipped.
WRVR	6275 ₈	WRITE VECTOR REGISTER Description: AC bits 0-10 are transferred to the Vector Register and the AC is cleared.
CAF	6007 ₈	CLEAR ALL FLAGS—clears F7E and W0F (and also COF), Clock enable and clock buffer. The DMA process is initiated if the status register is not set to the "stop" mode.

TABLE 4 DMA FLAGS AND STATUS REGISTER BIT ASSIGNMENTS

	, 0 ,	1	2	3	4	5	6	· 7	8	9	10	11	
	•	•	•	•	•	F7E	WOF	SR7	SR8	CE	R/W	IE	
	whe	re* -	- dor	h't ca	are fo	or wr	ite a	nd z	ero f	or re	ad.		
=71	Ξ	- 	Fielç CAF	17 , RF	wrap SR	arc and	nund RE	carı SET	y er	ror;	clea	red	by
NO	/0F Logic one indicates word counter overflow clear by CAF, LWCR and RESET												
CE	E Carry enable from CA(0-11) to ECA; cleared by RESET												
₹/\ E	V .		Logio ory t Enat	c one ranst ole ir	e indi fer). hterru	icate Clear upt v	s DN red (when ed by	IA w DMA WC V RE	rite ARea over SFT	(Por ad) b flow	t to l by R vs or	Vem ESE Fiel	- T d 7
SR	7,8	·	00	Re	fresh	mc	ode;	WC	is	froz	en, i	กอ่ไ	JP

- DMAEN is don't care 01 Normal mode: DMAEN(H) freezes WC
 - 01 Normal mode; DMAEN(H) freezes WC CA and no UP if WC has not overflowed; stop if WC overflows
 - 10 Burst mode; DMAEN(H) freezes WC, CA and no UP if WC has not overflowed; refresh condition if WC overflows

DMA MODES

SR7 = SR8 = 0 REFRESH MODE

This is the mode to which the 6102 reverts on RESET. The word count register clock input is disabled, the user pulse (DMA data strobe) is suppressed and the DMAEN input is ignored. However, provided valid DMA transfer conditions are met in a particular memory cycle, the DMA sequencer will be started, appropriate timing signals will be generated and the current address register will be clocked. Thus DMA read accesses will be performed continually with an essentially free-running current address register. Read accesses will refresh dynamic memory. No WOF is possible but an F7E is possible if bit SR9 is set, enabling a carry from the current address register to the extended current address register.

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SR7 = 0; SR8 = 1 NORMAL MODE

This mode is used for normal SDMA operations with static memory. The following instruction sequence can be used:

CLA	/Clear AC	5 6
TAD CA	/Get starting address	
LCAR	/Load into current address register clear AC	and

11 Stops DMA

TAD SR/Get DMA status Register ConstantLFSR/Change status (from refresh to normal
for example)TAD WC/Get two's complement of block length

LWCR /Load word count register and start DMA TRANSFERS

Note that LWCR will start the sequencer so it should be the last instruction in the initialization sequence. The ECA register and vector register could also have been initialized in this sequence.

The SDMA sequencer samples DMAEN on the rising edge of every XTA and latches the condition of the enable line. If DMAEN is low, the sequencer is enabled, external timing signals XTC*, MSEL*, UP, LXMAR* are generated, the WC and CA registers are clocked. If DMAEN is high, at XTA (\uparrow) time, the signal is sampled and latched and if the WC has not overflowed, the WC and CA registers are frozen, UP is suppressed. If the WOF condition comes up, the SDMA operation stops, regardless of DMAEN level.

The DMAEN and UP signals provide a simple interlocked handshaking method for transferring data one or more characters at a time (entire blocks) concurrently with processor operations on the bus. Of course, at all times, independent of DMAEN, the SDMA sequencer can proceed only if other bus usage conditions for DMA operations are met (not IOTA, IAUTOI, DCA, JMS, IJMS, ISZ, DMAGNT, or access of location X0000g),

NOTE: IAUTOI is an indirect cycle of any autoindexed instruction; IJMS is indirect cycle of JMS. An autoindexed JMP instruction may not be executed when the DMA mode is active.

SR7 = 1; SR8 = 0 BURST MODE

This mode is the same as the normal mode except when the word count register overflows. When this happens, the SDMA sequencer will set the WOF flag and revert to the refresh mode (ignoring DMAEN, freezing WC and suppressing UP). This mode is used when SDMA operations and dynamic memory refresh must be concurrently performed. The system designer must control the block lengths to be transferred, the refresh interval, and memory system design according to the application and performance desired.

SR7 = 1; SR8 = 1 STOP MODE

In this mode, no SDMA operations will take place. Naturally, cycle stealing DMA is still possible, and indeed may be used in any of the modes but the designer must be aware that cycle stealing may adversely affect dynamic memory refresh intervals. LWCR and LFSR may be executed in either order to change mode and start DMA.

B. Extended Memory Address Control

Figure 4 shows the EMA registers in more detail along with the register transfers caused by various instructions. The EMA function of the IM6102 is program compatible with the DEC PDP-8/E KM8-E Memory Extension option. The purpose of the EMA function is to extend the effective

addressing space of the system from 4K to 32K words. To perform this function, the EXTENDED MEMORY CON-TROLLER maintains a 3-bit extended address which is decoded by the memory modules to select 1 of 8 memory fields each containing 4096 words of storage. These 4K fields start with FIELD 0 and progress to FIFLD 7 when

fields start with FIELD 0 and progress to FIELD 7 when 32K of memory is used. All software communication with the controller is via programmed IOT instructions for which a summary is included in Table 1.

Figure 4 shows two 3-bit field registers: the Instruction Field, which acts as an extension to the Instruction and directly obtained operand addresses and the Data Field, which augments indirectly obtained operand addresses. The program can, therefore, use one field for instructions and address pointers and another field for data. The selection between Instruction and Data Fields is signalled by the DATAF signal generated by the IM6100. A discussion of the various registers follows.



FIGURE 4: EMA REGISTERS

INSTRUCTION FIELD REGISTER (IF)

The IF is a 3-bit register that serves as an extension of the Program Counter (PC). The IF, however, is not incremented when the PC goes from 77778 to 00008. The contents of the IF determine the field from which all instructions are taken. Operands for all directly addressed memory reference instructions also come from the Instruction Field. The indirect pointer for all indirectly addressed memory reference instructions reside in the Instruction Field. The IF is cleared to 0g and the IM6100 Program Counter is set to 77778 by RESET.

DATA FIELD REGISTER (DF)

The DF is a 3-bit register which determines the memory field from which operands are fetched in indirectly addressed AND, TAD, ISZ or DCA instructions. However, the branch address for indirectly addressed JMS or JMP instructions is obtained from the Instruction Field. The Data Field register may be modified under program control. The DF is set to O_8 , on reset.

INSTRUCTION BUFFER REGISTER (IB)

The IB is a 3-bit register which serves as an input buffer for the Instruction Field (IF) register. All programmed modifications of the IF register are made through the IB

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register. The transfer from IB to IF takes place at the beginning of the execute phase of the "next" JMP or JMS instruction or immediately upon execution of an LIF instruction. Using this feature, a program seqment can execute an instruction to modify the IF and then "exit" the program segment before the actual modification of the IF takes place. If instructions could change the IF directly, it would be impossible to execute the "next" sequential instruction, followed by a Change IF instruction. The IB to IF transfer is inhibited if the JMP/JMS instruction is fetched from control panel memory, which is restricted to 4K, but the LIF instruction is used here to provide the ability to load the IF register from the IB register. This allows the control panel routines to be executed transparently while the IB and IF differ and also yields a method for the panel to extract or alter the status of the primary EMA registers. The IB is set to Og, on reset. The IB to IF transfer takes place during the second cycle of a JMP/ JMS instruction when XTC makes a falling (+) transition.

SAVE FIELD REGISTER (SF)

The SF is a 6-bit register in which the IB and DF registers are saved during an Interrupt Grant. When an Interrupt occurs, the contents of IB and DF are automatically

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stored in SF (0-2) and SF (3-5), respectively, and the IF, IB and DF registers are cleared. The INTGNT (Interrupt Grant) cycle stores the "current" Program Counter (PC) in location 0000g of Memory Field 0g and the CPU resumes operation in location 0001g of Memory Field 0g. The Instruction Field and Data Field of the program segment being executed by the CPU before the interrupt was acknowledged are available in the SF register.

INTERRUPT INHIBIT FLIP-FLOP

The INTREQ (Interrupt Request) line to the IM6100 must be "gated" by the Interrupt Inhibit Flip Flop so that, when the Instruction Field is changed under program control, all interrupts are disabled until a JMP or JMS instruction is executed. Since the actual modification of the Instruction Field takes place only after the "next" JMP/JMS, this inhibition of the INTREO's ensures that the program sequence resumes operation in the "new" memory field before an Interrupt Request is granted.

Since Interrupt Requests are asynchronous in nature, a situation may arise in which an INTREQ is generated when the IF and IB bits are different. The Interrupt Inhibit FF guarantees the structural integrity of the program segment. The IIF is cleared on reset.

MNEMONIC	OCTAL CODE	OPERATION
GTF	6004 ₈	GET FLAGS
		$\begin{array}{llllllllllllllllllllllllllllllllllll$
RTF	6005 ₈	RETURN FLAGS
		Operation: LINK ← AC (0) IB ← AC (6-8) DF ← AC (9-11)
	ч _л	Description: LINK is restored. All AC bits are available externally during IOTA T6 to restore other flag bits. The internal Interrupt System is enabled. However, the Interrupt Inhibit FF is made active until the "next" JMS/JMP/LIF. The IB is transferred to IF after the "next" JMS/JMP/LIF.
CDF	62N18	CHANGE DATA FIELD
		Operation: $DF \leftarrow N_8$
	•	Description: Change DF register to N (08-78).

TABLE 5 EMA INSTRUCTIONS

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TABLE 5, Continued

CIF 62N28 CHANGE INSTRUCTION FIELD Operation: IB ← Ng Description: Change IB to N (0g-7g). Transfer IB to IF after the "next JMP/JMS/LIF. The Interrupt Inhibit FF is active until the JMP/JMS/LIF.	, "next"
Operation: IB ← Ng Description: Change IB to N (0g-7g). Transfer IB to IF after the "next JMP/JMS/LIF. The Interrupt Inhibit FF is active until the JMP/JMS/LIF. CDE_CLE 62N2c CHANCE DE_LE	, "next"
Description: Change IB to N (08-78). Transfer IB to IF after the "next JMP/JMS/LIF. The Interrupt Inhibit FF is active until the JMP/JMS/LIF.	, "next"
Operation: $DF \leftarrow N_8$ $IB \leftarrow N_8$ Description: Combination of CDE and CLE	
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	
Description: OR's the contents of DF into bits 6-8 of the AC. All other are unaffected.	bits
RIF 62248 READ INSTRUCTION FIELD	
Operation: AC (6-8) \leftarrow AC (6-8) + IF	
Description: OR's the contents of IF into bits 6-8 of the AC. All other the AC are unaffected.	bits of
RIB 62348 READ INTERRUPT BUFFER READ SAVE FIELD	
Operation: AC (6·11) ← AC (6·11) + SF	
Description: OR's the contents of SF into bits 6-11 of the AC. All other bits are unaffected.	n a second
RMF 62448 RESTORE MEMORY FIELD	1.
Operation: IB ← SF (0·2) DF ← SF (3·5)	
Description: The SF register saves the contents of the IB and DF wh an interrupt occurs. This command is used to restore IE and DF when "exiting" from the interrupt service rout in another field.	en B ne
Transfer IB to IF after the next JMP/JMS/LIF. The Interrupt Inhibit Flip-Flop is active until the next JMP/JMS/LIF.	
LIF 62548 LOAD INSTRUCTION FIELD	2
Operation: IF ← IB	. ;
Description: Transfer IB to IF and clear the Interrupt Inhibit FF	

١,

+: "OR" •: "AND"

←: "IS REPLACED BY"

OPERAND FETCHING

Instructions are accessed from the currently assigned Instruction Field. For indirect AND, TAD, ISZ or DCA instructions, the operand address refers first to the Instruction Field to obtain an Effective Address which in turn refers to a location in the currently addressed Data Field. All instructions and operands are obtained from the field designated by the IF, except for indirectly addressed operands, which are specified by the DF.

Thus, DF is active only in the Execute phase of an AND, TAD, ISZ or DCA when it is directly preceded by an Indirect phase.

ADDRESS MODE	IF	DF	AND, TAD, ISZ or DCA
Direct	m	n	Operand in field m
Indirect	m	n	Absolute address of operand in field m; operand in field n

Each field of extended memory contains eight auto-index registers in addresses 10 through 17. For example, assume that a program in field 2 is running (IF = 2) and using operands in field 1 (DF = 1) when the instruction TAD I 10 is fetched. The indirect autoindex cycle is entered, and the contents of location 10 in field 2 are read, incremented, and rewritten. If address 10 in field 2 originally contained 0546, it now contains 0547. In the execute cycle, the operand is fetched from location 0547 of field 1.

Program control is transferred between memory fields by the CIF instruction. The instruction does not change the instruction field directly, as this would make it impossible to execute the next sequential instruction; instead, it loads the new instruction field in the IB for automatic transfer into the IF when either a JMP or JMS instruction is executed. The DF is unaffected by the JMP and JMS instructions.

The 12-bit program counter is set in the normal manner and, because the IF is an extension on the most significant end of the PC, the program sequence resumes in the new memory field following a JMP or JMS. Entry into a program interrupt is inhibited after the CIF instruction until a JMP or JMS is executed.

NOTE: The IF is not incremented if the PC goes from 7777_8 to 00008. This feature protects the user from accidentally entering a nonexistent field.

To call a subroutine that is out of the current field, the data field register is set to indicate the field of the calling JMS, which establishes the location of the operands as well as the identity of the return field. The instruction field is set to the field of the starting address of the subroutine. The following sequence returns program control to the main program from a subroutine that is out of the current field.

/PROGRAM OPERATIONS IN MEMORY FIELD 2 /INSTRUCTION FIELD = 2; DATA FIELD = 2

/CALL A SUBROUTINE IN MEMORY FIELD 1 /INDICATE CALLING FIELD LOCATION BY THE /CONTENTS OF THE DATA FIELD **CIE 10** /CHANGE TO INSTRUCTION /FIFI D 1 = 6212/SUBRP = ENTRY ADDRESS JMS I SUBRP CDF 20 /RESTORE DATA FIELD SUBRP. SUBR POINTER FIELD 2 FIELD 1 /CALLED SUBROUTINE. /LOCATION IN FIELD 1 SUBR. **/RETURN ADDRESS** n /STORED HERE CLA RDF /READ DATA FIELD INTO AC TAD RETURN /CONTENTS OF THE AC = /6202 + DATA FIELD BITS /STORE CIF N INSTRUCTION DCA EXIT /NOW CHANGE DATA FIELD /IF DESIRED

When a program interrupt occurs, the current instruction and data field numbers are automatically stored in the 6-bit save field register, then the IF and DF are cleared. The 12-bit program counter is stored in location 0000g of field 0g and program control advances to location 0001g of field 0g. At the end of the program interrupt subroutine, the RMF instruction restores the IF and DF from the contents of the SF. Alternatively, the GTF and RTF instructions may be used to handle the Save Field and Link information. The following instruction sequence at the end of the program interrupt subroutine continues the interrupted program after the interrupt has been processed:

/A CIF INSTRUCTION

/PROGRAM

/INSTRUCTION

/RETURN TO CALLING

/USED TO FORM CIF N

•	
CLA	
TAD	AC
RMF	
ION	

EXIT,

RETURN, CIF

JMP I SUBR

JMP I O

/RESTORE AC /LOAD IB AND DF FROM SF /TURN ON INTERRUPT /SYSTEM /RESTORE PC WITH /CONTENTS OF LOCATION /00008 AND LOAD /IF FROM IB



IM6100 control panel memory programs, if used must be careful in the manner that EMA register data is manipulated. Control panel interrupt requests bypass the device interrupt enable flip flop, and indeed, are granted even by a halted CPU. The interrupts from a control panel may occur at any time, and in particular when the IB and IF registers do not contain the same data. The EMA logic inhibits IB to IF transfers in control panel memory so that panel routines may execute transparently (in particular, JMP/JMS instructions). The panel routines may alter the IF by executing the LIF instruction.

Users should also note that the GTF and RIB instructions read the SF register, and only the RIF instruction reads the IF register. Note also that the SF saves the IB register rather than the IF during an interrupt. However, interrupts are inhibited until the IF and IB registers are the same.

The memory extension controller that we have discussed in this section shows three important design considerations involved in extending memory addressing space. The first is the concept of having separate instruction and data fields for program flexibility. The second is the importance of double buffering the instruction field register to maintain structural integrity of programs and the third is the provision for saving the current field status upon interrupts and disabling interrupts until a change of instruction field has been completely executed.

C. Programmable Real Time Clock

The programmable real time clock offers the 6100 user a number of ways to accurately measure and count intervals in order to implement real time data acquisition and data processing systems.

The crystal used should have the following characteristics:

R_S ≤ 150 ohms

 $C_{M} = 3-30 \text{ mpF} (10-15F)$

 $C_O = 10-50 \text{ pF}$ Static capacitance should be around 5pF; for the greatest stability, C_O should be around 12pF and the oscillator

is parallel resonant.

ASSIGNMENTS

0	1	2	3	4	5	6	7	8	9	10	11
ENO	•	EN2	EN3	EN4	EN5	•	EN7	•	•	·	·

* Don't care for write and zero for read.

Where EN0 -

When set to 1, enables clock overflow (COF flag) to cause an interrupt. Cleared by RESET, CAF.

EN2 --

When reset to a 0-counter runs at selected rate. Overflow occurs every 4096 (2¹²) counts.COF flag remains set until cleared by IOT 6135 (CLSA), CAF, RESET.

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When set to a 1-counter runs at selected rate. If the COF flag is cleared, overflow causes clock buffer to be transferred to the clock counter which continues to run. COF flag remains set until cleared with IOT 6135 (CLSA). Also cleared by RE-SET, CAF.

Assuming 2 MHz crystal oscillator cleared

EN3, 4, 5 –

by RESET, CAF.

Bits 3,4,5	Octal	Interval Between Pulses	Frequency
000	0	Stop	0.
001	1	Stop	0
010	2	20 msec	50 Hz
011	·3	2 msec	500 Hz
100	4	200 µsec	5 KHz
101	5	20 µsec	50 KHz
110	6,	2 µsec	500 KHz
111	7	Stop	0,

EN7 – Inhibits clock prescaler when set to 1 cleared by RESET, CAF. EN3-5 and EN7 should not be changed simultaneously.



FIGURE 5 RTC REGISTERS

A discussion of the Real Time Clock registers as shown in Fig. 5 follows:

CLOCK ENABLE REGISTER

This register controls the mode of counting, whether clock interrupts are allowed, and the rate of the time base of the clock. For a description refer to the register bit assignments.

CLOCK BUFFER REGISTER (CB)

This 12-bit register stores data being transferred from the AC to the clock counter, or from the clock counter to the AC. It also permits presetting of the clock counter.

CLOCK COUNTER REGISTER (CC)

This register is a 12-bit binary counter that may load the clock buffer or be loaded from it. It is driven by a 2 MHz crystal oscillator with the proper predivision set by the time base selection. When an overflow occurs and if bit 0 of the clock enable register is a logic one, an interrupt is requested. If bit 2 is also 1, overflow causes the clock buffer to be transferred automatically into the clock counter.



TIME BASE MULTIPLEXER

The multiplexer provides count pulses to the clock counter according to the rate set by the clock enable register. Use of other than a 2 MHz crystal for the clock will result in proportionately different time bases.

CLOCK OVERFLOW FLAG

This flag is set by a clock counter overflow. It is cleared by CAF, CLSA and RESET. Its complement provides LSB (VR11) of interrupt vector. If ENO of clock enable counter is set, COF can cause an interrupt request. The COF is set when the MSB of the counter makes a "1" to "0" transition.

TABLE 7 RTC INSTRUCTIONS

MNEMONIC	OCTAL CODE	OPERATION
CLZE	6130 ₈	CLEAR ENABLE REGISTER PER AC Description: Clears the bits in the clock enable register corresponding to those bits set in the AC. The AC is not changed.
CLSK	61318	SKIP ON CLOCK INTERRUPT Description: Causes the program counter to be incremented by one if clock interrupt conditions exists, so that the next sequential instruction is skipped.
CLOE	6132 ₈	SET ENABLE REGISTER PER AC Description: Sets the bits in the clock enable register corresponding to those bits set in the AC. The AC is not changed.
CLAB	6133 ₈	TRANSFER AC TO CLOCK BUFFER Description: Causes the contents of the AC to be transferred to the Clock Buffer, then causes the contents of the Clock Buffer to be transferred to the Clock Counter. The AC is not changed.
CLEN	6134 ₈	READ CLOCK STATUS Description: Interrogates the clock overflow status flip flop by clearing AC, then transferring clock status into AC bit 0. COF is cleared.
CLSA	6135 ₈	READ CLOCK STATUS Description: Interrogates the clock overflow status flip flop by clearing AC, then transferring clock status into AC bit O. COF is cleared.
CLBA	6136 ₈	READ CLOCK BUFFER Description: Clears the AC, then transfers the contents of the Clock Buffer into the AC.
CLCA	6137 ₈	READ CLOCK COUNTER Description: Clears the AC, transfers the contents of the Clock Counter to the Clock Buffer, then transfers the contents of the Clock Buffer into the AC. If EN7 is set to 1 (clock prescaler is inhibited), the CLCA instruction increments the prescaler input by one. If the clock is in the "stop" mode but EN7 is not inhibited, the prescaler will not be clocked by the CLCA instruction.
CAF	6007 ₈	CLEAR ALL FLAGS Description: Clears COF flag (and also F7E, WOF flags), clock enable and clock buffer registers.

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IM6102

SYSTEM CONSIDERATIONS

The IM6102 is the highest priority device in a priority interrupt scheme. It provides an active low signal on pin 40, POUT, to signal the next lower priority device in the chain (thus, a high level on POUT indicates that the 6102 is not requesting an interrupt) via its "priority-in", PRIN, input.

The IM6102 when requesting an interrupt activates the SKP/INT line low on pin 35 and the POUT line low on pin 40 if its interrupt inhibit flip-flop is not set.

The IOT instructions used by the IM6102 preclude the use of certain device addresses when the system uses IM6101 PIEs. The addresses that may not be used are those given by bits 3 through 7 of the IOT instructions that are used with the IM6102. These addresses are 00101, 01000, 01001, 01010, 01011 corresponding to IOT instructions 612X, 613X, 620X, 621X, 622X, 623X, 624X, 625X, 626X and 627X.

The IM6102 does not generate DMAREQ signals to the 6100 because of its simultaneous use of the DX bus. It monitors the DMAGNT signal in order to place the EMA 0, 1, 2 lines on pins 36, 37, 38 in a high impedance state while DMAGNT is high.

If the application requires other peripherals requiring direct memory access on a cycle stealing basis, for example, bus contention problems will be resolved by the IM6102 as it monitors the DMAGNT line and gets off the bus (by placing all lines in the high impedance state) when DMAGNT is active.

If interrupts are enabled and a request is pending, during the first INTGNT cycle, the IM6102 will detect the referencing of location 0000g by the IM6100 in order to save the PC and will suspend simultaneous DMA during that cycle. The logic will in fact suspend simultaneous DMA in any cycle that location 0000g is referenced, either in main memory or control panel memory.

This makes it possible to disable automatic interrupt vectoring by grounding the INTGNT line to the IM6102. This will not affect the generation of INTREQ so the IM6100 will have to poll peripheral devices (skip on flag instructions) to determine the interrupting source.

Grounding INTGNT is not possible in extended memory applications since the INTGNT signal is used to save the Instruction Buffer and Data Field Register and clear the IF, IB and DF registers. (All peripheral device interrupt service routines have their entry point at location 00018 of Memory Field 08).

If no interrupt requests are pending in the 6102 (COF, F7E or WOF) from the DMA or RTC functions, the IM6102 interrupt request flip-flop is clear and POUT, the priority out signal, is high, enabling interrupt requests downstream in the priority chain. In the event that interrupts are enabled (DMA status bit SR11 is set and/or clock enable bit ENO is set) and an interrupting condition occurs (F7E, WOF, COF), the POUT signal goes low asynchronously disabling interrupt vectors downstream.

If the Interrupt Inhibit Flip-Flop is not set, the SKP/INT line is driven low by the interrupt request. If the IIFF is set, the SKP/INT line stays high until the IIFF is cleared (by RESET or an IB to IF transfer) at which time SKP/INT may be driven low. Skip requests will always propagate independently of IIFF during IOTA •DEVSEL• XTC.

Interrupt requests from devices downstream of the IM6102 must also be channeled via the IM6102 in order that the IIFF may condition the request timing. The IM6102 provides a built in pull-up on the SKP/INTX line coming in from devices downstream in the priority chain. At 5v, the pull-up looks like a 10K resistor; at 10V, it looks like 5K.

The execution of any IOT instruction will reset INTGNT to a low level at the end of IOTA time. This IOT instruction will be the first instruction in the interrupt service routine after saving status. If hardware vectoring is being used, any IOT instruction when INTGNT is high will cause the IM6102 to place a vector address on the bus if it requested an interrupt and pull the C1 and C2 lines low, thus placing the vector in PC and forcing a branch to the service routine. If the C2 line is left unconnected, the vector address will not be forced into the PC, but will be OR'ed into the AC. The interrupt service routine would have to execute a CLA after its first IOT instruction in order to clear the AC. Note that the LSB of the vector address is determined by the complement of the COF flag and that a DMA interrupt service routine must distinguish between the two possible interrupting conditions, a word count overflow or a field 7 wraparound error. The programmer may read the DMA status register with an RFSR instruction and also test the WOF flag with a skip instruction, SKOF. The COF flag may also be tested with the CLSK skip instruction. The flag may be read (and cleared) with the CLSA instruction. The skip instructions cause the SKP/INT line to go low during IOTA XTC time if the flag being tested is set. At all other times, the SKP/INT line carries interrupt requests as modified by the IM6102 interrupt inhibit logic. The flags must always be explicitly cleared by the interrupt service routine.

The DMA transfer rate depends on the program. The minimum rate would be obtained if the processor was executing an autoindexed DCA or an indirect JMS (even if non-autoindexed, DMA is suppressed during indirect phase of JMS). Continuously executing these instructions would cause DMA transfers to occur only every third memory cycle (IFETCH). The maximum rate could be obtained by executing a JMP• loop (JMP to itself); data would be transferred on every cycle and the interrupt routine entered when word count overflows could bump the return address out of the loop.

In dynamic memory systems it should be noted that the MEMSEL* signal narrows when the mode changes from write to refresh (burst mode). RESET signals may need to be limited in duration to prevent loss of memory data in dynamic memory systems.

The accuracy of the clock counter in the programmable real time clock section of the IM6102 is as follows:

CASE 1: Counter running; CC loaded from AC via CB using instruction CLAB (IOT 6133) accuracy is 0 to +1 count.

CASE 2: CC loaded from CB automatically on overflow; the accuracy of counting is

then only dependent on accuracy of oscillator.

IM6102 users who do not need all the capabilities of the device may improve systems performance by not using some of the features. To do this properly, certain pins on the device will become unused. The following table summarizes what may be done with certain pins when using only part of the IM6102 functions. All unlisted pins must be used when implementing any of the three basic features.

·····					
PIN NUMBER	PIN NAME	RTC ONLY	SDMA ONLY	EMC ONLY	EMC & DYNAMIC REFRESH
2	DMAEN DMAGNT	GND USED	USED USED	GND USED	GND
6	MEMSEL*	N/C	USED	N/C	USED
· 8 · ·	UP	N/C	USED	N/C	N/C
11 .	LXMAR*	N/C	USED	N/C	USED
12	XTC*	N/C	USED	N/C	USED
- 15	SKP/INTX	VCC	VCC	USED	USED
29	OSCIN	USED	GND .	GND	GND
31	OSC OUT	USED	N/C	N/C	N/C
34	C2	USED	USED	N/C	N/C
36	EMAO	N/C	N/C	USED	USED
37	EMA 1	N/C	N/C	USED	USED
38	EMA 2	N/C	N/C	USED	USED
40	PROUT	USED	USED	N/C	N/C

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TABLE 1 SUMMARY OF IM6102 INSTRUCTIONS

	OCTAL	1/0 0	ONTROL L	INES	
MNEMONIC	CODE	C0	C1	C2	OPERATION
GTF	6004	0	0	. 1	(1) Get flags, INT INH FF \rightarrow AC(3), SF (0.5) \rightarrow AC(6.11)
RTF	6005	1	1	. 1	(2) Return flags, AC(6-8) \rightarrow IB, AC(9-11) \rightarrow DF
CDF	62N1	1	1	1	Change Data Field, $N \rightarrow DF$
CIF	62N2	• 1	. 1	. 1	Change IF, $N \rightarrow IB$
CDF, CIF	62N3	. 1	1	1	Combination of CDF, CIF
RDF	6214	. 1	.0	1	Read DF, DF + AC(6-8) \rightarrow AC(6-8)
RIF	6224	, 1	0	.1	Read IF, IF + AC(6-8) →AC(6-8)
RIB	6234	1	0	1	Read Save Field, SF + AC(6-11) \rightarrow AC(6-11)
RMF	6244	1	1	1	Restore Mem. Field, SF(0-2) \rightarrow IB, SF(3-5) \rightarrow DF
LIF	6254	1	`1.	1.	Load IF, IB → IF
CLZE	6130	1	1	1	Clear Clock Enable Register if corresponding AC bit is set AC not changed
CLSK	6131	1	1	1	Skip on Clock Overflow Interrupt condition
CLOE	6132	1	1	1	Set Clock Enable Register if corresponding AC bit is set
					AC not changed
CLAB	6133	1	1	1	AC \rightarrow Clock Buffer; Clock Buffer \rightarrow Clock Counter;
		1. 1. A. 1.			AC not changed
CLEN	6134	0	0	1	Clock Enable Register → AC
CLSA	6135	Ű	0	1	$COF \rightarrow AC(0)$, Clear COF Status bit
CLBA	6136	0	0	1	Clock Buffer → AC
CLCA	6137	0	0	1	Clock Counter → Clock Buffer; Clock Buffer → AC
LCAR	6205	0	1	1	$AC \rightarrow Current Address Register, 0 \rightarrow AC$
RCAR	6215	0	0	1	Current Address Register → AC
LWCR	6225	0	1	1	AC \rightarrow Word Count Register, Start DMA, 0 \rightarrow AC; clears word
a the second second)		count overflow (WOF)
LEAR	62N6	1	1	1 .	$N \rightarrow Extended Current Address Register (ECA)$
REAR	6235	· 1	0	1	Read ECA, ECA + AC(6-8) \rightarrow AC(6-8)
LFSR	6245	0	1	1	AC(7-11) \rightarrow Status Register, 0 \rightarrow AC
RFSR	6255	1	0	1 ;	DMA Status Register + AC(5-11) \rightarrow AC(5-11); clears Field 7
1.1					Wraparound error (F7E)
SKOF	6265	1	1	1	Skip on Word Count Overflow
WRVR	6275	0	1	1	$AC(0.10) \rightarrow Vector Register, 0 \rightarrow AC$
CAF	6007	1	1	<u> </u>	3 Clear all flags (F7E, W0F, COF) Clear clock Enable
			÷		register, clock butter

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NOTES:

1. The internal flags of the IM6100 are defined as follows: LINK \rightarrow AC (0), INTREQ \rightarrow AC (2) and INTERRUPT ENABLE FF \rightarrow AC (4). 2. When RTF is executed, the LINK is restored from AC (0) and the Interrupt System is enabled after the next sequential instruction is executed. The Interrupt Inhibit FF is set preventing interrupts until the next JMP, JMS or LIF instruction is executed.

3. A hardware RESET clears F7E, W0F, 11FF and COF. The IF and DF are cleared to Og. The DMA status register is cleared. (Read; refresh; disable F7E and W0F interrupts; no carry from CAO to ECA2). The clock Enable register is cleared (Disable COF interrupt; disable clock buffer to clock counter transfer on COF; disable counter). Counter/buffer is cleared.

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TABLE 2 SUMMARY OF IM6102 REGISTER BIT ASSIGNMENTS

	DX0	DX1	DX2	DX3	DX4	DX5	DX6	DX7	DX8	DX9	DX10	DX11
Current Address	CA0	CA1	CA2	CA3	CA4	CA5	CA6	CA7	CA8	CA9	CA10	CA11
Extended Current Address						1	ECA0	ECA1	ECA2	• . • . •		
Word Count	WCO	WC1	WC2	WC3	WC4	WC5	WC6	WC7	WC8	WC9	WC10	WC11
DMA Status (1)						SR5	SR6	SR7	SR8	SR9	SR10	SR11
Interrupt Vector (2)	VR0	VR1	VR2	VR3	VR4	VR5	VR6	VR7	VR8	VR9	VR10	VR11
RIF Instruction (3)			· .				IFO	IF1	IF2	•	· ·	1.1
RTF, CIF Instruction				1 24 · ·			1B0	IB1	IB2			
GTF, RIB Instruction				FF(4)			SF0	SF1	SF2	SF3	SF4	SF5
CDF, RDF Instruction							DF0	DF1	DF2		4	
RTF Instruction										DFO	DF1	DF2
Clock Enable (5)	ENO	1.51	EN2	EN3	EN4	EN5		EN7				
Clock Buffer	CB0	CB1	CB2	CB3	CB4	CB5	CB6	CB7	CB8	CB9	CB10	CB11
Clock Overflow (6)	COF											

(1)DMA STATUS READ F7E; cleared by CAF, RFSR (at IOTA · XTC time), RESET SR5 Set if Field 7 wraparound carry error -ONLY SR6 Set if DMA Word Counter Overflow -WOF; cleared by CAF, LWCR, RESET BITS SR7 Mode Bit 7) ; Cleared by RESET (REFRESH MODE) SR8 Mode Bit 8 € See below SR9 Carry enable from CA0-11 to ECA2 if set - CE SB10 DMA Write if set SR11 Enable F7E or W0F interrupt if set - IE (2)VR0-VR10 loaded from AC. VR11 is equivalent to COF (3)IF --Instruction Field; cleared to 0g by RESET AND INTGNT Interrupt Inhibit Flip-Flop; set whenever IB \neq IF; (CIF, CDF/CIF, RMF, RTF) cleared by RESET (4)HEE and IB → IF transfer EN0 --Enable Clock Overflow (COF) interrupt; cleared (interrupt disable) by RESET, CAF (5)EN2 -When set causes clock buffer to be transferred to clock counter on COF. Counter runs at selected rate; COF remains set until cleared with CLSA. When cleared to 0, counter runs at selected rate, overflow occurs every 212 counts and COF remains set. EN2 is cleared by RESET, CAF EN3, EN4, EN5 - Select interval between pulses. Cleared to 000 by RESET (counter disabled), CAF See below. EN7 - Inhibits clock prescaler when set. Cleared by RESET, CAF COF - Clock Overflow status bit; cleared by CAF, RESET and CLSA; complement provides LSB of interrupt vector, (6) 2 MHz clock SR 7,8 00 Refresh mode; WC is frozen, no UP, DMAEN don't care EN 3, 4,5 with STOP 01 Normal mode; DMAEN(H) freezes WC, CA and no 000 STOP UP if WC has not overflowed; stop if WC overflows 001 10 Burst mode; DMAEN (H) freezes WC, CA and no 010 20 ms interval UP if WC has not overflowed; reverts to refresh 011 2 ms interval 200 µs interval mode if WC overflows. 100 20 μ s interval 11 Stops SDMA 101 110 2 µs interval STOP 111

NOTES:

1. Bits SR 7 and 8 do not change when the DMA controller stops or reverts to refresh mode as a result of WC overflow.

2. The "overflow" status is defined as set when the most significant bit of a counter makes a "1" to "0" transition.

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SDMA OPERATIONS TIMING

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. DMA W	LXMAR MEMSEL UP XTC DX		ADDRESS ROM IM6100		READ D TO ING	 ATA 100	REFRE	SH ADDRE DM IM6102	SS	MORY DATA
. DMA W	LXMAR' MEMSEL' UP XTC' DX Vrite LXMAR'		ADDRESS ROM IM6100		READ D TO IMS		REFRE FRC	ISH ADDRE SM IM6102	SS MEN	MORY DATA
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. DMA W	LXMAR*		ADDRESS ROM IM6100		READ TO IMS	ATA, 100	MWS FRC	SH ADDRE SH ADDRE M IM6102	SS MEN TOWAT	MORY DATA
. DMA W	LXMAR' MEMSEL' UP XTC' DX Vrite LXMAR' MEMSEL' Vite/Refr LXMAR' MEMSEL'				READ D TO IM6	ATA 100 100 ATA 100	REFRE FRC	SH ADDRESS M IM6102	towar towar towar towen twu	MORY DATA
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DMA W	LXMAR*				READ D TO IM6	ATA 100 100 ATA 100	REFRE FRC	ADDRES MIMGIO2	towat towat towat towen twu twu twu	MORY DATA

IM6102 TIMING DIAGRAM





IM6102A

ABSOLUTE MAXIMUM RATINGS

Operating Temperature	
Industrial IM6102A	40° C to +85° C
Storage Temperature	65° C to 150° C
Operating Voltage	+4.0V to +11.0V
Supply Voltage	+12.0V
Voltage On Any Input or	a da ser da la ser a
Output Pin	-0.3V to Vcc +0.3V

NOTE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent device failure. These are stress ratings only and functional operation of the devices at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may cause device failures.

D.C. CHARACTERISTICS

TEST CONDITIONS: $V_{CC} = 10V \pm 5\%$, $T_A = -40^{\circ}C$ to $+85^{\circ}C$

	SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS
		Input Voltage High	• •	70% Vcc			.ν.
2	VIL	Input Voltage Low		1		20% Vcc	V
3	liL	Input Leakage 1	GND≤V _{IN} ≤V _{CC}	-1.0		1.0	μA
. 4	Ион	Output Voltage High 2	IOH = 0mA	Vcc-0.01			V a
5	Vol	Output Voltage Low	IoL = 0mA			GND+0.01	V
	IOL .	Output Leakage	GND≤Vout≤Vcc	-1.0		1.0	μA
7	lcc	Power Supply Current-Standby	VIN=GND or Vcc	• • • • •	1.1	900	μA
8	lcc	Power Supply Current-Dynamic	fc = 5.71MHz			4.0	mA
.9	CIN	Input Capacitance 1			7.0	8.0	pF
10	Co	Output Capacitance 1			8.0	10.0	pF

NOTE: 1. Except pins 15, 29, 31 2. Except pins 32, 33, 34.

A.C. CHARACTERISTICS

TEST CONDITIONS: $V_{CC} = 10V \pm 5\%$, $C_L = 50pF$, $T_A = -40^{\circ}C$ to $+85^{\circ}C$, $f_C = 5.71MHz$

	SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS
1	tLIN	LXMAR Pulse Width IN	125			ns
2	tais	Address Setup Time IN: DX-LXMAR (1)	50			ns
3	tain	Address Hold Time IN: LXMAR(1)-DX	50			ns
4	tden (Data Output Enable Time: DEVSEL(1)-DX			240	ns
5	t CEN	Controls Output Enable Time: DEVSEL(1)-lines C0,C1,C2,S/I	1. A.		240	ns
6	tois	Data Input Setup Time: DX-DEVSEL(1)	50	1		ns
7	TDIH	Data Input Hold Time: DEVSEL(1)-DX	50			ns
8	trst	RESET Input Pulse Width	250			ns
9	tsid	SKP/INTX to SKP/INT Propagation Delay			100	· ns
10	TDMLX	DMA Control Signals Delay: XTC-XTC*; MEMSEL-MEMSEL*, LXMAR-LXMAR*			100	ns
11	t DEM	Enable/Disable Time from DMAGNT to EMA Lines			50	ns
12	tMDR	MEMSEL* Pulse Width READ	300			ns
13	tMDW	MEMSEL* Pulse Width WRITE	380			ns
14	tMDWR	MEMSEL* Pulse Width WRITE/REFSH	240			ns
15	tLD	LXMAR* Pulse Width	150		1.0	ns
16	tDRAT	DMA READ Access Time: LXMAR*(1)-UP(1)	300			ns
17	tdxas	DX & EMA Address Setup Time Wrt LXMAR*(1)	150			ns
18	tdxaн	DX & EMA Address Hold Time Wrt LXMAR*(1)	55			ns
19	tDREN	DMA READ Enable Time: MEMSEL* (1)-UP(1) ~	210			ns
20	trup	UP Pulse Width DMA READ	150	·		ns
21	TDWAT	DMA WRITE Access Time: LXMAR*(1)-MEMSEL*(1)	300			ns
22	towen	DMA WRITE Enable Time: UP (1)-MEMSEL*(1)	210			ns
23	tmws	MEMSEL* Setup Time DMA WRITE MEMSEL*(1)-LXMAR*(1)	50			ns
24	toms	DMAEN Setup Time Wrt XTA (1)	50			ns
25	tомн	DMAEN Hold Time Wrt XTA (1)	50			ns
26	twup	UP Pulse Width DMA WRITE	300			ns

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IM6102-1

ABSOLUTE MAXIMUM RATINGS

Operating Temperature	a de la composición d
Industrial IM6102-11	-40° C to +85° C
Storage Temperature	-65° C to 150° C
Operating Voltage	+4.0V to +7.0V
Supply Voltage	V0.8+
Voltage On Any Input or	
Output Pin0.	3V to Vcc +0.3V

NOTE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent device failure. These are stress ratings only and functional operation of the devices at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may cause device failures.

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D.C. CHARACTERISTICS

TEST CONDITIONS: $V_{CC} = 5.0V \pm 10\%$, $T_A = -40^{\circ}C$ to $+85^{\circ}C$

	SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
1;	Viн	Input Voltage High		Vcc-2.0			v
2	VIL	Input Voltage Low				20% Vcc	V
3	liL'	Input Leakage[1]	GND≤VIN≤Vcc	-1.0		1.0	μA
4	Vон	Output Voltage High 2	I _{OH} = -0.2mA	Vcc-0.01			V
5	Vol	Output Voltage Low	I _{OL} = 2.0mA		·	GND+0.01	V
6	IOL	Output Leakage	GND≤Vout≤Vcc	-1.0		1.0	μA
7	lcc	Power Supply Current-Standby	VIN=GND or Vcc	10.10.10 M		800	μA
8	lcc	Power Supply Current-Dynamic	fc = 3.33MHz	and the	10 - J	2.0	mA
9	CIN	Input Capacitance[1]			7.0	8.0	pF
10	Co	Output Capacitance 1			8.0	10.0	. pF

A.C. CHARACTERISTICS

TEST CONDITIONS: 5.0V \pm 10%, C_L = 50pF, T_A = -40°C to +85°C, f_C = 3.33MHz

	SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS
1:	tLIN	LXMAR Pulse Width IN	250			ns
2	tais	Address Setup Time IN: DX-LXMAR (4)	70	111	alle e	ns
3	tAIH	Address Hold Time IN: LXMAR(4)-DX	100		100	ns
4	tDEN :	Data Output Enable Time: DEVSEL(1)-DX	144		350	ns
5.	TCEN	Controls Output Enable Time: DEVSEL(1)-lines C0,C1,C2,S/I	and the second		350	ns
6	tois	Data Input Setup Time: DX-DEVSEL(1)	100	a for a set so	an sati ana	ns
7	TDIH	Data Input Hold Time: DEVSEL(1)-DX	100		the state of the	ns
8	trst	RESET Input Pulse Width	500	t gat i	a far	ns
9	tsid	SKP/INTX to SKP/INT Propagation Delay	a ser en		120	ns
10	tdmlx.	DMA Control Signals Delay: XTC-XTC*; MEMSEL-MEMSEL*, LXMAR-LXMAR*			120	ns
11	t DEM	Enable/Disable Time from DMAGNT to EMA Lines			80	ns
12	tMDR	MEMSEL* Pulse Width READ	550	6. j.		ns
13	tMDW	MEMSEL* Pulse Width WRITE	700	1. A. 1. M.		ns
14	TMDWR	MEMSEL* Pulse Width WRITE/REFSH	400			ns
15	tLD	LXMAR* Pulse Width	260	<u>,</u> 1.		ns
16	t DRAT	DMA READ Access Time: LXMAR*(1)-UP(1)	85			ns
17	tdxas	DX & EMA Address Setup Time Wrt LXMAR*(1)	125	1.1.4	a an an an an an	ns
18	tdxah .	DX & EMA Address Hold Time Wrt LXMAR*(1)	125			ns
19	tDREN	DMA READ Enable Time: MEMSEL* (1)-UP(1)	400	1.1.	an an taon an t	ns
20	tRUP	UP Pulse Width DMA READ	260	Contra da C		ns
21	TDWAT	DMA WRITE Access Time: LXMAR*(1)-MEMSEL*(1)	550			ns
22	towen	DMA WRITE Enable Time: UP (1)-MEMSEL*(1)	400			ns
23	tmws	. MEMSEL* Setup Time DMA WRITE MEMSEL*(4)-LXMAR*(4)	100			ns
24	toms .	DMAEN Setup Time Wrt XTA (1)	100			ns
25	tdмн	DMAEN Hold Time Wrt XTA (1)	100	1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 -	1	ns
26	twup	UP Pulse Width DMA WRITE	550			ns

IM6102

ABSOLUTE MAXIMUM RATINGS

Operating Temperature	الأنا أركبت وجراري
Industrial IM6102	40° C to +85° C
Storage Temperature	-65° C to 150° C
Operating Voltage	+4.0V to +7.0V
Supply Voltage	+8.0V
Voltage On Any Input or	e internet
Output Pin	-0.3V to V _{CC} +0.3V

NOTE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent device failure. These are stress ratings only and functional operation of the devices at these or any other conditions above those indicated in the operation sections of this specification "is not implied. Exposure to absolute maximum rating conditions for extended periods may cause device failures.

D.C. CHARACTERISTICS

TEST CONDITIONS: V_{CC} = 5.0V \pm 10%, T_A = -40°C to +85°C

	SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
1	Viн	Input Voltage High		Vcc-2.0			V
2	VIL	Input Voltage Low		· · · · · · · · · · · · · · · · · · ·		0.8	V
3	hL.	Input Leakage 1	GND≤VIN≤Vcc	-1.0		1.0	μA
4	Voн	Output Voltage High 2	loн = -0.2mA	2.4		100 C	ν.
5	VOL	Output Voltage Low	$I_{OL} = 2.0 \text{mA}$		•	0.45	v
6	IOL	Output Leakage	GND≤Vout≤Vcc	-1.0		1.0	μA
7	Icc	Power Supply Current-Standby	VIN=GND or Vcc	2000 - 14 A	1.0	800	μA
8	Icc	Power Supply Current-Dynamic	fc = 2.5MHz		$ _{\mathcal{O}} = _{\mathcal{O}}$	1.8	mA
9	Cin	Input Capacitance 1	· · ·		. 7.0	8.0	pF
10	Co	Output Capacitance 1			8.0	10.0	pF

NOTE: 1. Except pins 15, 29, 31 2. Except pins 32, 33, 34.

A.C. CHARACTERISTICS

TEST CONDITIONS: 5.0V \pm 10%, C_L = 50pF, T_A = -40°C to +85°C, f_C = 2.5MHz

	SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS
1	tLIN	LXMAR Pulse Width IN	300	· · · ·		ns
2	tais	Address Setup Time IN: DX-LXMAR (4)	80	and the	eg kaj 👘	ns
3	tain	Address Hold Time IN: LXMAR(1)-DX	120	 A second s	, I,	ns
4	tDEN	Data Output Enable Time: DEVSEL(4)-DX	1.1.1.1.1.1.1		400	ns
5	tCEN .	Controls Output Enable Time: DEVSEL(1)-lines C0,C1,C2,S/I		1	400	ns
6	tDIS	Data Input Setup Time: DX-DEVSEL(1)	100	fra a se		ns
7	TDIH	Data Input Hold Time: DEVSEL(1)-DX	100	1.4	1997 - 19	ns
8	tRST,	RESET Input Pulse Width	500			ns
9	tsiD	SKP/INTX to SKP/INT Propagation Delay			150	ns
10	TDMLX	DMA Control Signals Delay: XTC-XTC*; MEMSEL-MEMSEL*, LXMAR-LXMAR*	این اور داد. په افغان داد		150	ns
11	t DEM	Enable/Disable Time from DMAGNT to EMA Lines	ge kak	· ·	100	ns
12	t _{MDR}	MEMSEL* Pulse Width READ	750		1. 1. A.	ns
13	tMDW	MEMSEL* Pulse Width WRITE	950			ns
14	tMDWR	MEMSEL* Pulse Width WRITE/REFSH	550	1.1		ns
. 15	tLD	LXMAR* Pulse Width	350			ns
16	TORAT	DMA READ Access Time: LXMAR*(1)-UP(1)	750		23	ns
17	tDXAS	DX & EMA Address Setup Time Wrt LXMAR*(1)	120	5 1. Maria	11 1. J	ns
18	tDXAH	DX & EMA Address Hold Time Wrt LXMAR*(1)	175			ns
19	tOREN	DMA READ Enable Time: MEMSEL* (1)-UP(1)	550	S. A. Ash	1	ns
20	TRUP	UP Pulse Width DMA READ	350		1997 - 18	ns ,
21	tDWAT:	DMA WRITE Access Time: LXMAR*(1)-MEMSEL*(1)	750	1.200		ns
22	towen	DMA WRITE Enable Time: UP (1)-MEMSEL*(1)	550			ns
23	tmws	MEMSEL* Setup Time DMA WRITE MEMSEL*(1)-LXMAR*(1)	100		and the second s	ns
24	toms	DMAEN Setup Time Wrt XTA (1)	100			ns
25	tомн	DMAEN Hold Time Wrt XTA (1)	100			ns
26	twup	UP Pulse Width DMA WRITE	750	an an		ns

IM6102AM (Military)

ABSOLUTE MAXIMUM RATINGS

 Operating Temperature Military IM6102AM
 -55°C to +125°C

 Storage Temperature
 -65°C to 150°C

 Operating Voltage
 +4.0V to +11.0V

 Supply Voltage
 +12.0V

 Voltage On Any Input or
 -0.3V to V_{CC} +0.3V

NOTE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent device failure. These are stress ratings only and functional operation of the devices at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may cause device failures.

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D.C. CHARACTERISTICS

TEST CONDITIONS: $V_{CC} = 10V \pm 5\%$, $T_A = -55^{\circ}C$ to $\pm 125^{\circ}C$ in 100 which is the second state of the second sta

	SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS
1	Viн	Input Voltage High	104 1 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4	70% Vcc		a di ta	V
2	VIL	Input Voltage Low			and a second	20% Vcc	V 🛀
3	li <u>r</u>	Input Leakage 1	GND≤VIN≤Vcc	-1.0	1.00	1.0	μA
4	Vон	Output Voltage High 2	IOH = 0mA	Vcc-0.01	1	1. A	۷.
5	VOL	Output Voltage Low	I _{OL} = 0mA			GND+0.01	v
6	IOL	Output Leakage	GND≤Vout≤Vcc	-1.0		1.0	μA
7.	Icc	Power Supply Current-Standby	VIN=GND or Vcc			900	μA
8	Icc	Power Supply Current-Dynamic	fc = 5.0MHz	1.1.1.1.1.1.1		4.0	mA
9	CIN	Input Capacitance 1	· · · · · · · · · · · · · · · · · · ·		7.0	8.0	pF
10	Co	Output Capacitance 1			8.0	10.0	pF

NOTE: 1. Except pins 15, 29, 31 2. Except pins 32, 33, 34.

A.C. CHARACTERISTICS

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TEST CONDITIONS: $V_{CC} = 10V \pm 5\%$, $C_L = 50pF$, $T_A = -55^{\circ}C$ to $+125^{\circ}C$, $f_C = 5.0MHz$

	SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS
1	tLIN	LXMAR Pulse Width IN	135	1.11		ns
2	tais	Address Setup Time IN: DX-LXMAR (4)	60	1	· · · · ·	ns
3	tain '	Address Hold Time IN: LXMAR(1)-DX	60	1.1.1.1.1.1		ns
4	tDEN .	Data Output Enable Time: DEVSEL(4)-DX		1.1.1640	260	ns
5	t CEN	Controls Output Enable Time: DEVSEL(1)-lines C0,C1,C2,S/I			260	ns
6	tDIS	Data Input Setup Time: DX-DEVSEL(1)	60	1974 a 19		ns
• 7	Трін	Data Input Hold Time: DEVSEL(1)-DX	60			ns
8	trst ,	RESET Input Pulse Width	250	f statute 🔤	2. 1. 1. 2. 1. 1	ns
9	tsip	SKP/INTX to SKP/INT Propagation Delay	te tra ti d	144,61	120	ns
10	t DMLX	DMA Control Signals Delay: XTC-XTC*; MEMSEL-MEMSEL*, LXMAR-LXMAR*			120	ns
11	tDEM .	Enable/Disable Time from DMAGNT to EMA Lines	1 ²	1 - 12 ¹ - 1	60	ns
12	tmdr ;	MEMSEL* Pulse Width READ	375			ns
13	tMDW	MEMSEL* Pulse Width WRITE	475	1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 -	1.4	ns
14	t MDWR	MEMSEL* Pulse Width WRITE/REFSH	275	1. 2. 2. 5	e a de la come	ins ins
15	tLD ···	LXMAR* Pulse Width	175	12.2.3.15	1	ns
16	t DRAT	DMA READ Access Time: LXMAR*(4)-UP(1)	375			ns
17	tdxas	DX & EMA Address Setup Time Wrt LXMAR*(4)	70	1. 18 1. 1	e de la	ns
18	tdxah	DX & EMA Address Hold Time Wrt LXMAR*(4)	70	ter dati	5 a 17	ns
19	tDREN	DMA READ Enable Time: MEMSEL* (1)-UP(1)	275	- 1 () + 124		ns
20	tRUP	UP Pulse Width DMA READ	175	an air an th		ns
21	t DWAT	DMA WRITE Access Time: LXMAR*(4)-MEMSEL*(1)	375	el d'est	1.1	ns
22	tDWEN	DMA WRITE Enable Time: UP (1)-MEMSEL*(1)	275	1.000	1.1.1	ns
23	tmws	MEMSEL* Setup Time DMA WRITE MEMSEL*(4)-LXMAR*(4)	50	1	i	ns
24	toms	DMAEN Setup Time Wrt XTA (1)	50	1. J 1	1	ns
25	tdмн	DMAEN Hold Time Wrt XTA (1)	50	14	1	ns
26.	twup	UP Pulse Width DMA WRITE	375	1. 1. 1. A. S.	a the state	ns

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IM6102-1M (Military)

ABSOLUTE MAXIMUM RATINGS

Operating Temperature	
Military IM6102-1M	55° C to +125° C
Storage Temperature	65° C to 150° C
Operating Voltage	+4.0V to +7.0V
Supply Voltage	+8.0V
Voltage On Any Input or	the second s
Output Pin	0.3V to Vcc +0.3V

NOTE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent device failure. These are stress ratings only and functional operation of the devices at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may cause device failures.

D.C. CHARACTERISTICS

TEST CONDITIONS: $V_{CC} = 5.0V \pm 10\%$, $C_L = 50pF$, $T_A = -55^{\circ}C$ to $\pm 125^{\circ}C$

)	SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS
1	ViH	Input Voltage High	1	Vcc -2.0	and and a second		v
2	VIL	Input Voltage Low				0.8	۷.
3	hĽ.	Input Leakage 1	GND≤VIN≤Vcc	-1.0		1.0	μA
4	Vон	Output Voltage High 2	IOH = 0mA	2.4			V
5	Vol	Output Voltage Low	I _{OL} = 0mA			0.45	V
6	loi.	Output Leakage	GND≤Vout≤Vcc	-1.0	1.1	1.0	μA
7:	Icc ·	Power Supply Current-Standby	VIN=GND or Vcc			800	μA
8	Icc .	Power Supply Current-Dynamic	fc = 2.5MHz			2.0	mA
9	CIN	Input Capacitance 1			7.0	8.0	рF
10	Co	Output Capacitance[1]	· · · · · · · · · · · · · · · · · · ·	1 - 1 - 1	8.0	10.0	рF

NOTE: 1. Except pins 15, 29, 31 2. Except pins 32, 33, 34.

A.C. CHARACTERISTICS

TEST CONDITIONS: $V_{CC} = 5.0V \pm 10\%$, $T_A = -55^{\circ}C$ to $+125^{\circ}C$, $f_C = 2.5MHz$

	SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS
1	tLIN	LXMAR Pulse Width IN	300			ns .
2	tais	Address Setup Time IN: DX-LXMAR (4)	80	1.8		ns .
3	tain	Address Hold Time IN: LXMAR(1)-DX	120	1	1.4	ns
4	tDEN	Data Output Enable Time: DEVSEL(1)-DX	1.00		400	ns
5	t CEN	Controls Output Enable Time: DEVSEL(1)-lines C0,C1,C2,S/I			400	ns
6	tois	Data Input Setup Time: DX-DEVSEL (1	100	i di di su		ns
7:	TDIH	Data Input Hold Time: DEVSEL 1 -DX	100	1997 - Ma		ns
8	tRST	RESET Input Pulse Width		1. 19 ¹ -	1. T.	ns
9	tsid	SKP/INTX to SKP/INT Propagation Delay	1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1	,	130	ns
10	TOMLX	DMA Control Signals Delay: XTC-XTC*; MEMSEL-MEMSEL*, LXMAR-LXMAR*		tan Marina Marina	130	ns
11	TDEM	Enable/Disable Time from DMAGNT to EMA Lines		1 ¹ .	100	ns
12	tMDR	MEMSEL* Pulse Width READ	750	1		ns
13	tMDW	MEMSEL* Pulse Width WRITE	950	. * .	17	ns
14	tMDWR,	MEMSEL* Pulse Width WRITE/REFSH	550	· .		ns
15	tLD	LXMAR* Pulse Width	350			ns
16	t DRAT	DMA READ Access Time: LXMAR*(1)-UP(1)	750	· · ·	1.	ns
17	tDXAS	DX & EMA Address Setup Time Wrt LXMAR*	120	8-3-		ns
18	tDXAH	DX & EMA Address Hold Time Wrt LXMAR* 1	175			ns
19	TOREN	DMA READ Enable Time: MEMSEL* (1)-UP(1)	550	1.1.1	1. S.	ns
20	tRUP	UP Pulse Width DMA READ	350		the second	ns
21	tDWAT .	DMA WRITE Access Time: LXMAR*(1)-MEMSEL*(1)	750	25		ns
22	towen	DMA WRITE Enable Time: UP (1)-MEMSEL*(1)	550	1 A. A.	. *	ns
23	tmws	MEMSEL* Setup Time DMA WRITE MEMSEL*(4)-LXMAR*(4)	100			ns
24	toms	DMAEN Setup Time Wrt XTA	100		1	ns
25	tомн	DMAEN Hold Time Wrt XTA (1)	100		• .	ns
26	twup	UP Pulse Width DMA WRITE	750			ns

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IM6102

APPLICATION

IM6100-IM6102 Interface in a Buffered System.

